General Purpose Transistors

PNP Silicon

BCH807-16L/25L/40L, NSVBCH807-16L/25L/40L

Features

- 175°C T_{J(max)} Rated for High Temperature, Mission Critical Applications
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector – Emitter Voltage | V _{CEO} | -45 | V |
| Collector – Base Voltage | V _{CBO} | -50 | V |
| Emitter – Base Voltage | V _{EBO} | -5.0 | V |
| Collector Current – Continuous | Ι _C | -500 | mAdc |
| Collector Current – Peak | I _{CM} | -800 | mA |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR-5 Board, (Note 1) T _A = 25°C Derate above 25°C | P _D | 225 1.3 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient (Note 1) | $R_{\theta JA}$ | 400 | °C/W |
| Total Device Dissipation Alumina Substrate, (Note 1) T _A = 25°C Derate above 25°C | PD | 300 1.8 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | 330 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +175 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

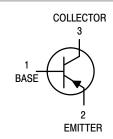
1. FR-4 Board, 1 oz. Cu, 100mm².

2. Alumina = 0.4 x 0.3 x 0.024 in 99.5% alumina.



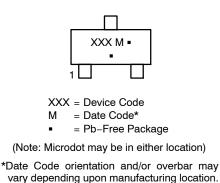
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MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

| Characteristic | Symbol | Min | Тур | Max | Unit |
|---|----------------------|------|-----|--------------|----------|
| OFF CHARACTERISTICS | | - | | | |
| Collector – Emitter Breakdown Voltage $(I_{C} = -10 \text{ mA})$ | V _{(BR)CEO} | -45 | - | _ | V |
| Collector – Emitter Breakdown Voltage (V _{EB} = 0, I _C = –10 μ A) | V _{(BR)CES} | -50 | - | - | V |
| Emitter – Base Breakdown Voltage (I _E = -1.0μ A) | V _{(BR)EBO} | -5.0 | _ | - | V |
| Collector Cutoff Current $(V_{CB} = -20 \text{ V})$ $(V_{CB} = -20 \text{ V}, \text{ T}_{J} = 150^{\circ}\text{C})$ | I _{CBO} | | | -100 -5.0 | nA μA |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain | h _{FE} | | | | - |

| DC Current Gain ($I_C = -100 \text{ mA}, V_{CE} = -1.0 \text{ V}$) | BCH807-16/NSVBCH807-16L* | h _{FE} | 100 | | 250 | - |
|---|--------------------------|----------------------|-----|---|------|---|
| (1C = -100 mA, VCE = -1.0 V) | BCH807-25/NSVBCH807-25L | | 160 | _ | 400 | |
| | BCH807-40/NSVBCH807-40L | | 250 | - | 600 | |
| $(I_{C} = -500 \text{ mA}, V_{CE} = -1.0 \text{ V})$ | | | 40 | - | - | |
| Collector – Emitter Saturation Voltage ($I_C = -500 \text{ mA}$, $I_B = -50 \text{ mA}$) |) | V _{CE(sat)} | - | - | -0.7 | V |
| Base – Emitter On Voltage (I _C = –500 mA, V _{CE} = –1.0 V) | | V _{BE(on)} | - | - | -1.2 | V |

SMALL-SIGNAL CHARACTERISTICS

| Current – Gain – Bandwidth Product ($I_C = -10 \text{ mA}, V_{CE} = -5.0 \text{ Vdc}, f = 100 \text{ MHz}$) | f _T | 100 | _ | _ | MHz |
|--|------------------|-----|----|---|-----|
| Output Capacitance (V _{CB} = -10 V, f = 1.0 MHz) | C _{obo} | 1 | 10 | - | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

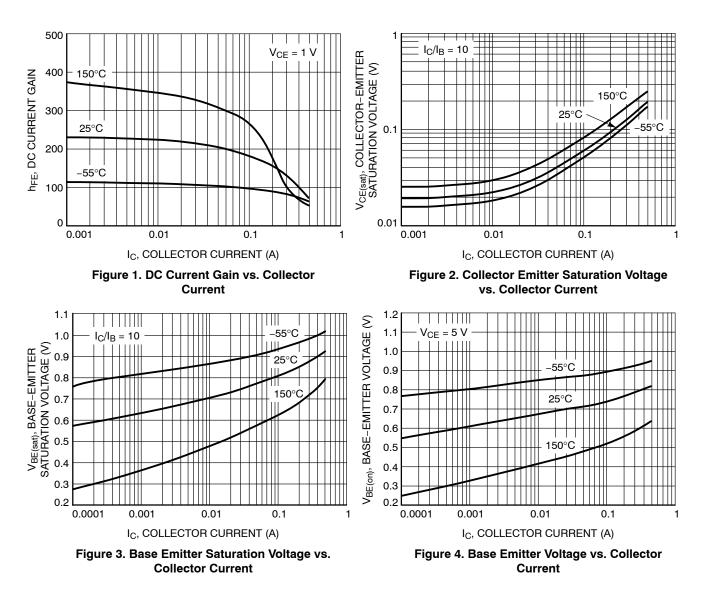
| Device | Specific Marking | Package | Shipping [†] |
|-----------------------|------------------|-----------|-----------------------|
| BCH807-16LT1G** | xxx | | |
| NSVBCH807-16LT1G*, ** | ~~~ | | 3000 / Tape & Reel |
| BCH807-25LT1G** | 5AG | SOT-23 | 3000 / Tape & Reel |
| NSVBCH807-25LT1G* | SAG | (Pb-Free) | SUUD / Tape & Reel |
| BCH807-40LT1G** | 5E | | |
| NSVBCH807-40LT1G* | 5E | | 3000 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

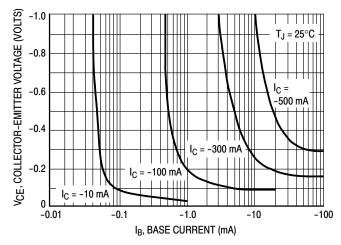
*NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

**Device release available upon request - Please contact ON Semiconductor sales.

TYPICAL CHARACTERISTICS – BCH807–16L



TYPICAL CHARACTERISTICS – BCH807–16L





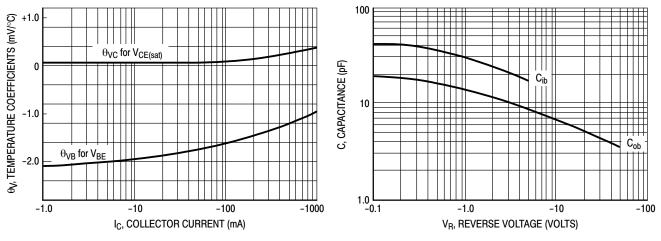
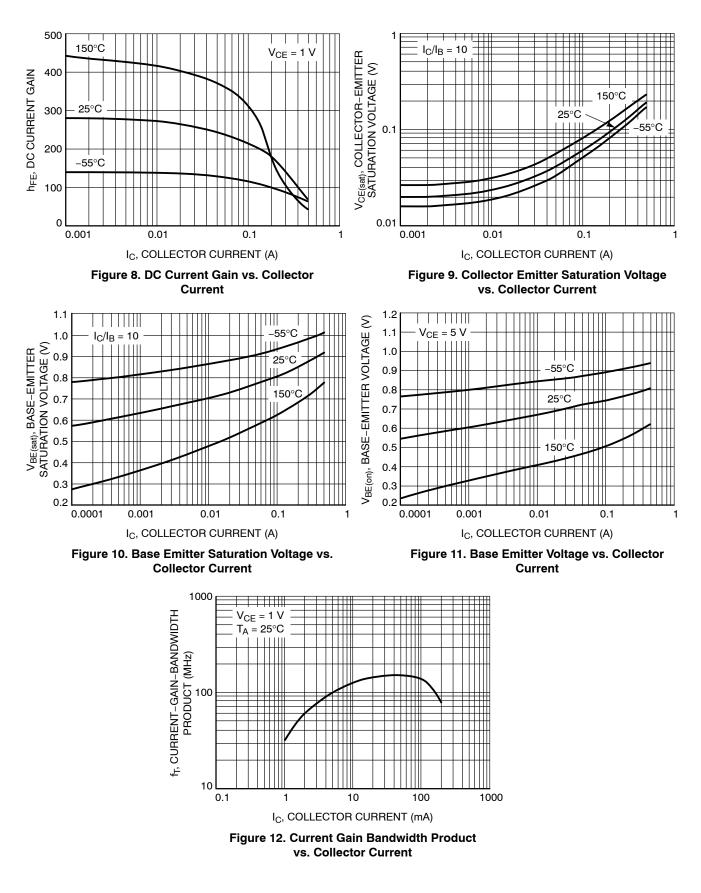


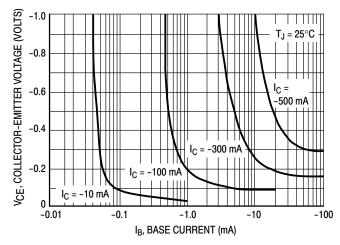
Figure 6. Temperature Coefficients

Figure 7. Capacitances

TYPICAL CHARACTERISTICS – BCH807–25L



TYPICAL CHARACTERISTICS – BCH807–25L





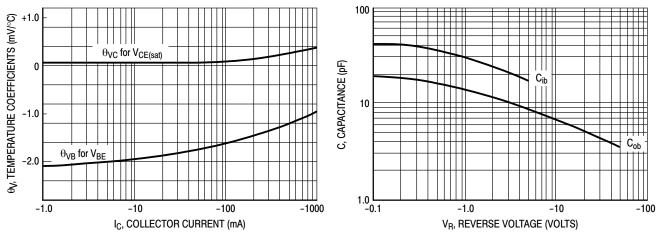
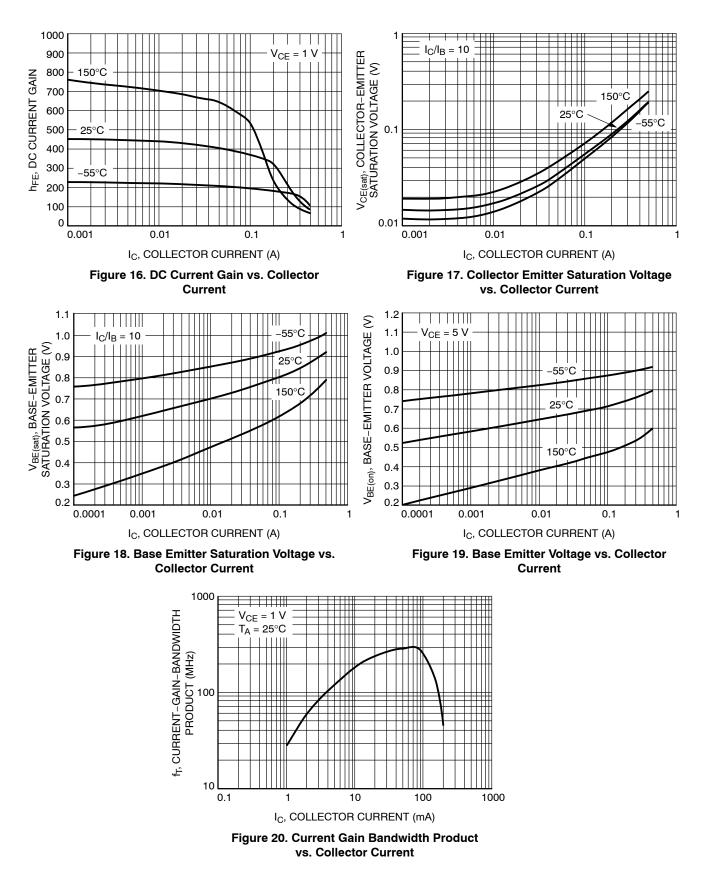


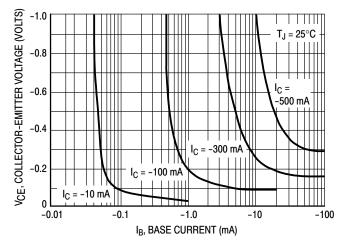
Figure 14. Temperature Coefficients

Figure 15. Capacitances

TYPICAL CHARACTERISTICS – BCH807–40L



TYPICAL CHARACTERISTICS – BCH807–40L





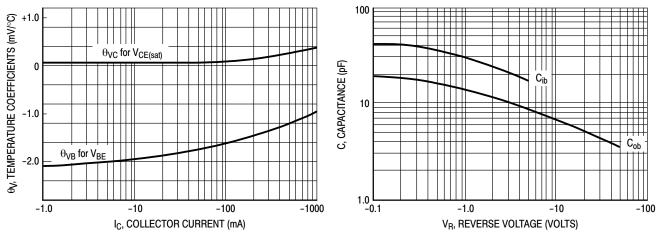
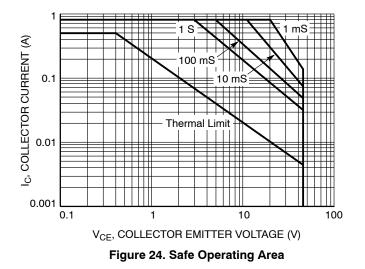


Figure 22. Temperature Coefficients

Figure 23. Capacitances

TYPICAL CHARACTERISTICS - BCH807-16L, BCH807-25L, BCH807-40L



MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

D

3

TOP VIEW

SIDE VIEW

Нe

DETAIL A

-3X b

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SCALE 4:1

A____ ' A1SOT-23 (TO-236) CASE 318 ISSUE AT

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DETAIL A

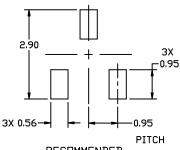
END VIEW

DATE 01 MAR 2023

NDTES

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIM | IETERS | | INCHES | | |
|----------------|--------|--------|------|--------|-------|-------|
| DIM | MIN. | NDM. | MAX. | MIN. | NDM. | MAX. |
| Α | 0.89 | 1.00 | 1.11 | 0.035 | 0.039 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.000 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.017 | 0.020 |
| с | 0.08 | 0.14 | 0.20 | 0.003 | 0.006 | 0.008 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.080 |
| L | 0.30 | 0.43 | 0.55 | 0.012 | 0.017 | 0.022 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.027 |
| H _E | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| Т | 0* | | 10* | 0* | | 10* |



RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

= Pb–Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

onsemi

SOT-23 (TO-236) CASE 318 ISSUE AT

DATE 01 MAR 2023

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR | STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE | | |
|---|---|---|--|------------------|------------------|
| STYLE 9: | STYLE 10: | STYLE 11: | STYLE 12: | STYLE 13: | STYLE 14: |
| PIN 1. ANODE | PIN 1. DRAIN | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. SOURCE | PIN 1. CATHODE |
| 2. ANODE | 2. SOURCE | 2. CATHODE | 2. CATHODE | 2. DRAIN | 2. GATE |
| 3. CATHODE | 3. GATE | 3. CATHODE-ANODE | 3. ANODE | 3. GATE | 3. ANODE |
| STYLE 15: | STYLE 16: | STYLE 17: | STYLE 18: | STYLE 19: | STYLE 20: |
| PIN 1. GATE | PIN 1. ANODE | PIN 1. NO CONNECTION | PIN 1. NO CONNECTION | PIN 1. CATHODE | PIN 1. CATHODE |
| 2. CATHODE | 2. CATHODE | 2. ANODE | 2. CATHODE | 2. ANODE | 2. ANODE |
| 3. ANODE | 3. CATHODE | 3. CATHODE | 3. ANODE | 3. CATHODE-ANODE | 3. GATE |
| STYLE 21: | STYLE 22: | STYLE 23: | STYLE 24: | STYLE 25: | STYLE 26: |
| PIN 1. GATE | PIN 1. RETURN | PIN 1. ANODE | PIN 1. GATE | PIN 1. ANODE | PIN 1. CATHODE |
| 2. SOURCE | 2. OUTPUT | 2. ANODE | 2. DRAIN | 2. CATHODE | 2. ANODE |
| 3. DRAIN | 3. INPUT | 3. CATHODE | 3. SOURCE | 3. GATE | 3. NO CONNECTION |
| STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE | STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE | | | | |

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